NSN 5961-01-250-8512

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-250-8512 **Inclosure Material:** Ceramic **Overall Length:** 0.120 inches **Terminal Length:** 0.024 inches **Overall Height:** 0.023 inches **Overall Width:** 0.055 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 2.5 reverse voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute **Transfer Ratio:** 25.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No